



### P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> T <sub>C</sub> = +25°C
-40V	15mΩ @ $V_{GS}$ = -10 $V$	-61A
-40 V	23mΩ @ $V_{GS} = -4.5V$	-49A

# **Description and Applications**

This new generation MOSFET has been designed to minimize the onstate resistance (RDS(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Reverse Polarity Protection
- **BLDC Motor Control**
- **Power Management Functions**

## **Features and Benefits**

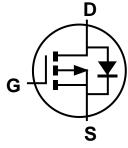
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMP4013SPSQ)

### **Mechanical Data**

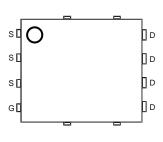
- Case: PowerDI®5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish 100% Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



Top View **Bottom View** 



Internal Schematic



Top View Pin Configuration

## **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMP4013SPS-13	PowerDI5060-8	2,500 / Tape & Reel

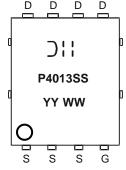
Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

Pin1

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain < 900ppm bromine, < 900ppm chlorine (< 1500ppm total Br + Cl) and
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

# **Marking Information**



);; = Manufacturer's Marking P4013SS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 19 = 2019)WW = Week (01 to 53)

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# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	$V_{DSS}$	-40	V		
Gate-Source Voltage	$V_{GSS}$	±20	V		
Continuous Drain Current V <sub>GS</sub> = -10V (Note 7)	Steady State	$T_C = +25$ °C $T_C = +70$ °C	ΙD	-61 -49	А
Continuous Drain Current V <sub>GS</sub> = -10V (Note 6)	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	Ι <sub>D</sub>	-11 -9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	-244	Α		
Maximum Body Diode Continuous Current (Note 7)			Is	-61	Α
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)			I <sub>SM</sub>	-244	Α
Avalanche Current (Note 8) L = 1mH			I <sub>AS</sub>	-16	Α
Avalanche Energy (Note 8) L = 1mH			E <sub>AS</sub>	176	mJ

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	$P_{D}$	1.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	96	°C/W
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	$P_{D}$	3.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	44	°C/W
Thermal Resistance, Junction to Case (Note 7)		R <sub>θJC</sub>	1.5	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-40			V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	-1	μΑ	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	$V_{GS(TH)}$	-1	_	-3	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance		_	9.6	15	mΩ	$V_{GS} = -10V, I_D = -10A$	
Static Dialif-Source Off-Nesistance	R <sub>DS(ON)</sub>	_	13.4	23	1112.2	$V_{GS} = -4.5V, I_D = -8A$	
Diode Forward Voltage	$V_{SD}$	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C <sub>iss</sub>	_	4004			V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V f = 1MHz	
Output Capacitance	Coss		309		pF		
Reverse Transfer Capacitance	Crss	_	229	_			
Gate Resistance	$R_{g}$	_	3.5	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	$Q_g$	_	31				
Total Gate Charge (V <sub>GS</sub> = -10V)	$Q_g$	_	67	_	nC	$V_{DS} = -20V,$	
Gate-Source Charge	$Q_{gs}$	_	13.2	_	IIC	$I_D = -10A$	
Gate-Drain Charge	$Q_{gd}$		11	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	9.9	_			
Turn-On Rise Time	t <sub>R</sub>		32	_	ns	$V_{GS} = -10V, V_{DD} = -20V,$ $R_G = 3\Omega, I_D = -10A$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	46	_	115		
Turn-Off Fall Time	t <sub>F</sub>	_	53	_			
Reverse Recovery Time	t <sub>RR</sub>	_	19.5		ns	I <sub>F</sub> = -10A, di/dt = -100A/μs	
Reverse Recovery Charge	$Q_{RR}$	_	11.6	_	nC	$I_F = -10A$ , di/dt = -100A/ $\mu$ s	

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
- 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 8.  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J$  = +25°C. 9. Short duration pulse test used to minimize self-heating effect.
- 10. Guaranteed by design. Not subject to product testing.



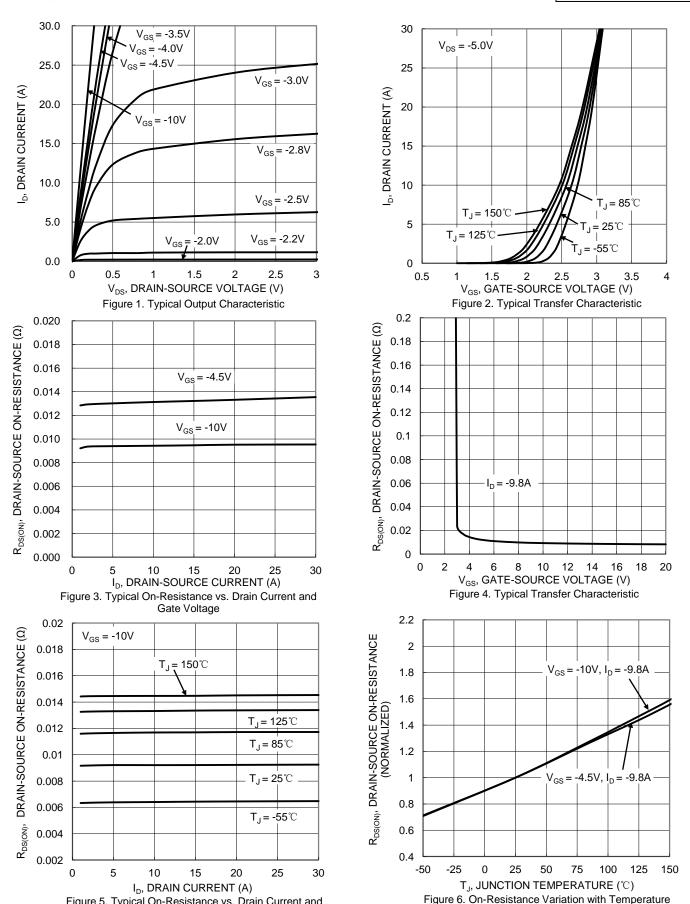


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

100

V<sub>DS</sub>, DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area



0

10

20

30

40

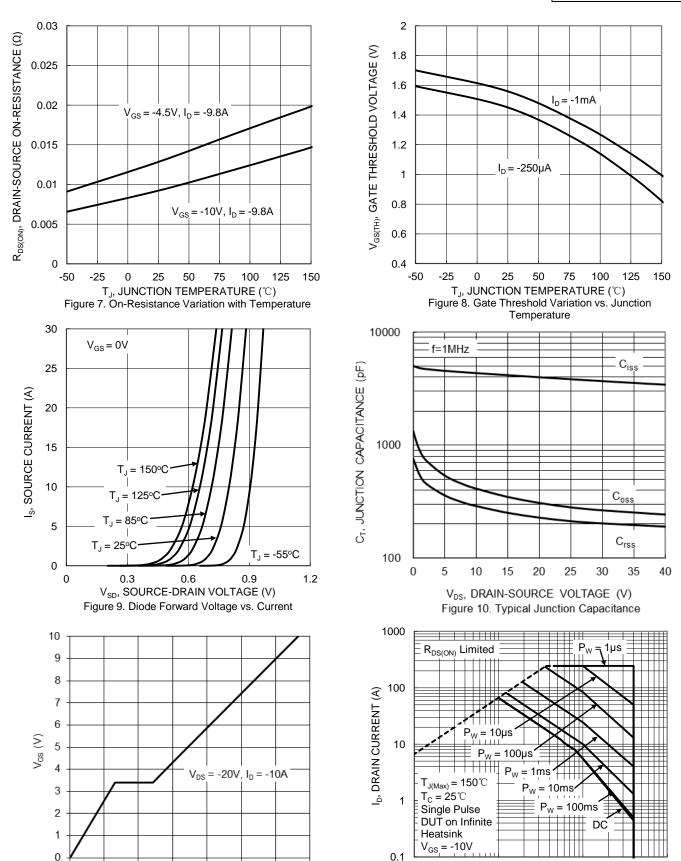
Qg (nC)

Figure 11. Gate Charge

50

60

70



0.1



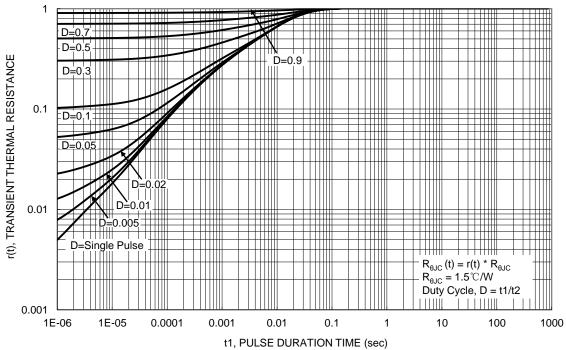


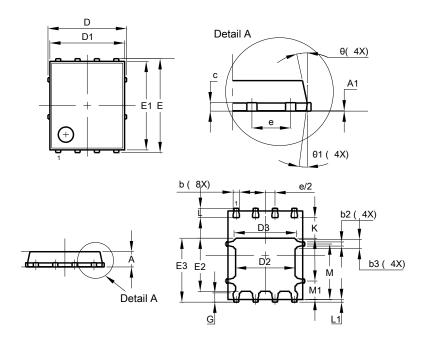
Figure 13. Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI5060-8

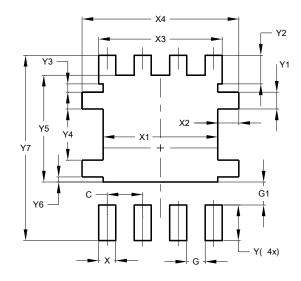


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	_		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	ţ	5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е		6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC			
G	0.51	0.71	0.61		
K	0.51	_	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
M	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All	All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8



Dimensions	Value (in mm)			
C	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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